

VHF variable capacitance double diode Rev. 03 — 1 July 2004

Product data sheet



1.1 General description

The BB804 is a variable capacitance double diode with a common cathode, fabricated in planar technology and encapsulated in the SOT23 small plastic SMD package.

1.2 Features

- Selected capacitance range
- Small plastic SMD package
- C8: 26 pF; ratio: 1.7
- Low series resistance.

1.3 Applications

Electronic tuning in FM radio applications.

Pinning information 2.

Table 1: **Pinning**

Pin	Description	Simplified outline	Symbol
1	anode (a1)		_
2	anode (a2)	3	3
3	common cathode	12 SOT23	1 - 1 - 2 - 2 - sym032

Ordering information 3.

Table 2: **Ordering information**

Type number	Package				
	Name	Description	Version		
BB804	-	plastic surface mounted package; 3 leads	SOT23		



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4. Marking

Table 3: Marking

Type number	Marking code [1]
BB804	16*

- [1] * = p: made in Hong Kong.
 - * = t: made in Malaysia.
 - * = W: made in China.

5. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode	•				
V_R	continuous reverse voltage		-	18	V
I _F	continuous forward current		-	50	mA
T _{stg}	storage temperature		-55	+150	°C
Tj	junction temperature		-55	+125	°C

6. Characteristics

Table 5: Characteristics

 $T_i = 25 \,^{\circ}C$ unless otherwise specified

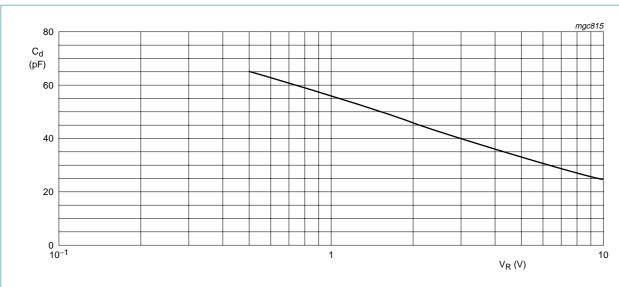
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _R	reverse current	see Figure 2				
		V _R = 16 V	-	-	20	nA
		V _R = 16 V; T _j = 60 °C	-	-	200	nA
r _s	diode series resistance	f = 100 MHz	[1]	0.2	-	Ω
C _d	diode capacitance	$V_R = 2 V$; $f = 1 MHz$; see Figure 1 and Figure 3	42	-	46.5	pF
$\frac{C_{d(2V)}}{C_{d(8V)}}$	capacitance ratio	f = 1 MHz	1.65	-	1.75	

^[1] V_R is the value at which C_d = 38 pF.

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f = 1 MHz; $T_j = 25 \,^{\circ}\text{C}$.

Fig 1. Diode capacitance as a function of reverse voltage; typical values.

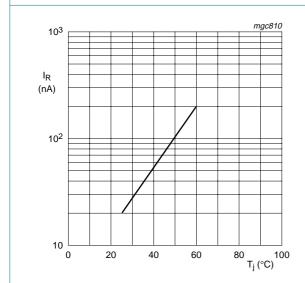


Fig 2. Reverse current as a function of junction temperature; maximum values.

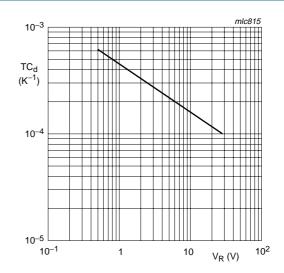


Fig 3. Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.

Package outline

Plastic surface mounted package; 3 leads

SOT23

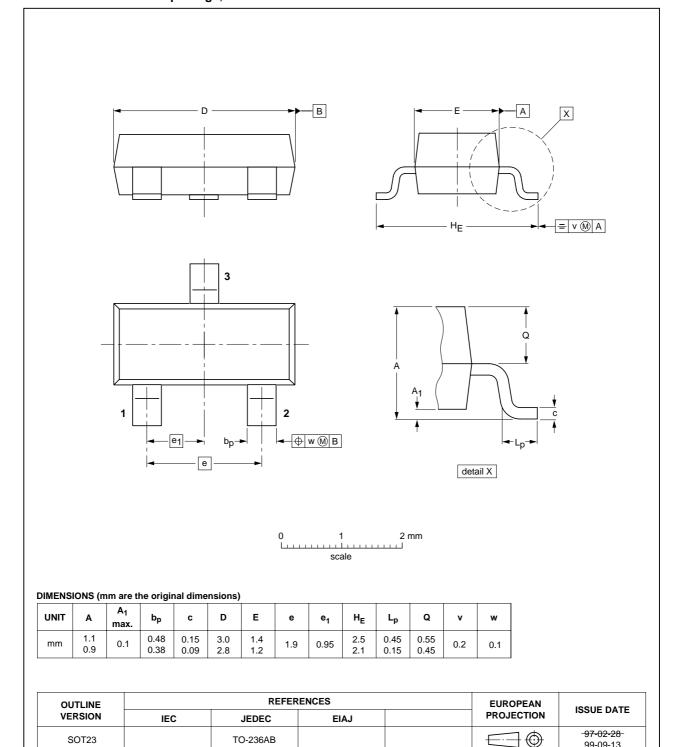


Fig 4. Package outline.

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8. Revision history

Table 6: Revision history

Document ID	Release date	Data sheet status	Change notice	Order number	Supersedes
BB804_3	20040630	Product data sheet	-	9397 750 13386	BB804_2
Modifications:	 The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors 				v presentation and
	 <u>Table 3</u>: m 	arking code changed.			
BB804_2	19981125	Product data sheet	-	9397 750 04717	BB804_1
BB804_1	19960503	-	-	-	-

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9. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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